

# NCV4299C

## Voltage Regulator - Low-Dropout

### 150 mA

The NCV4299C is a family of precision micropower voltage regulators with an output current capability of 150 mA. It is available in 5.0 V or 3.3 V output voltage.

The output voltage is accurate within  $\pm 2\%$  with a maximum dropout voltage of 0.5 V at 100 mA. Low Quiescent current is a feature drawing only 80  $\mu\text{A}$  with a 100  $\mu\text{A}$  load. This part is ideal for any and all battery operated microprocessor equipment.

The device features microprocessor interfaces including an adjustable reset output and adjustable system monitor to provide shutdown early warning. An inhibit function is available. With inhibit active, the regulator turns off and the device consumes less than 1.0  $\mu\text{A}$  of quiescent current.

The part can withstand load dump transients making it suitable for use in automotive environments.

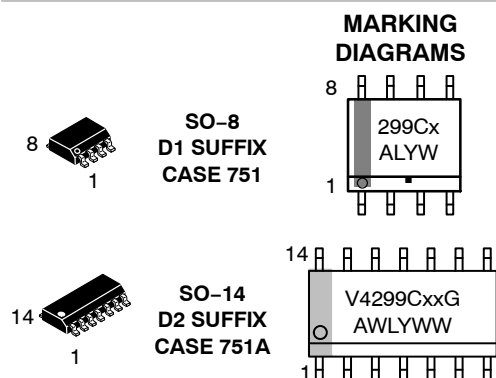
#### Features

- 5.0 V, 3.3 V  $\pm 2\%$ , 150 mA
- Extremely Low Current Consumption
  - ◆ 80  $\mu\text{A}$  (Typ) in the ON Mode
  - ◆ < 1.0  $\mu\text{A}$  in the Off Mode
- Early Warning
- Reset Output Low Down to  $V_Q = 1.0$  V
- Adjustable Reset Threshold
- Wide Temperature Range
- Fault Protection
  - ◆ 60 V Peak Transient Voltage
  - ◆ -40 V Reverse Voltage
  - ◆ Short Circuit
  - ◆ Thermal Overload
- Internally Fused Leads on SO-14 Package
- Inhibit Function with 1  $\mu\text{A}$  Current Consumption in the Off Mode
- AEC-Q100 Grade 1 Qualified and PPAP Capable
- These are Pb-Free Devices



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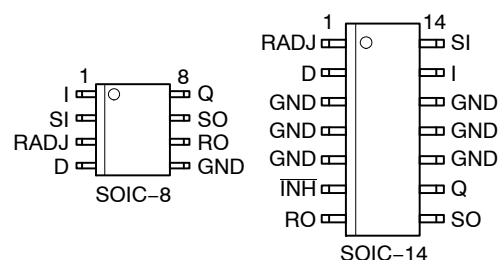
[www.onsemi.com](http://www.onsemi.com)



x, xx = 3 or 33 (3.3 V Version)  
= 5 or 50 (5.0 V Version)  
A = Assembly Location  
WL, L = Wafer Lot  
Y = Year  
WW, W = Work Week  
G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

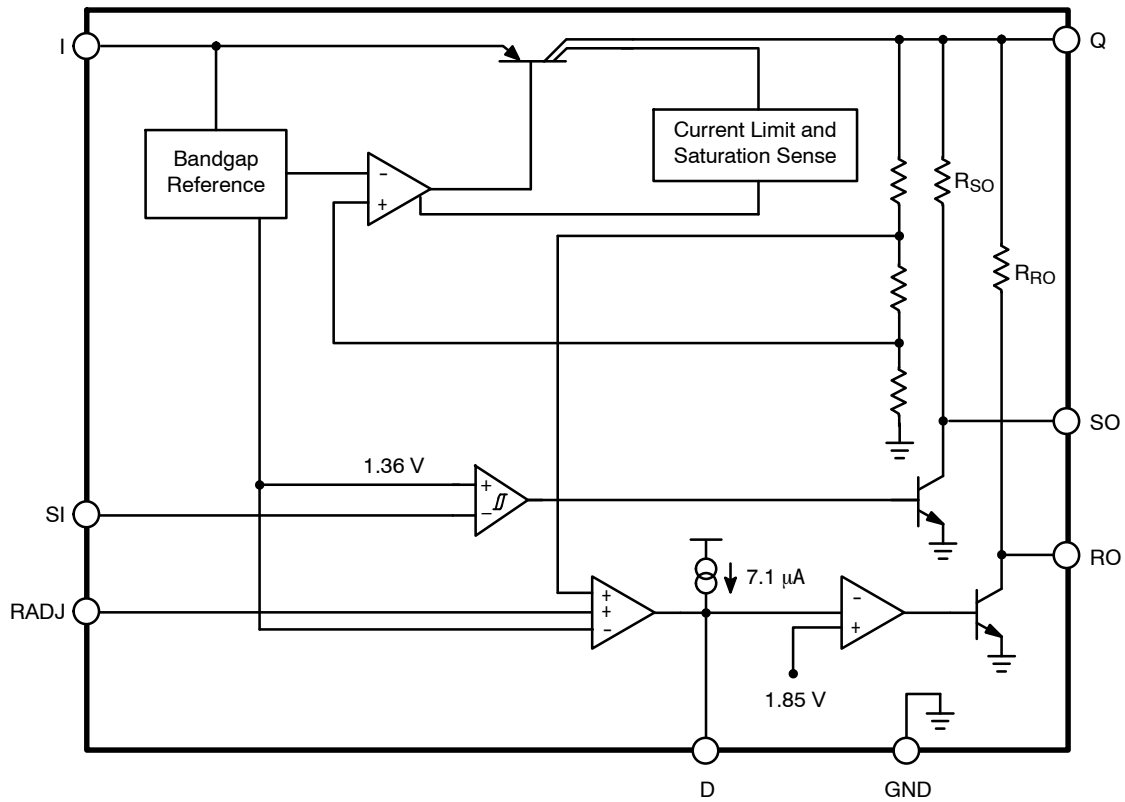
#### PIN CONNECTIONS



#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 17 of this data sheet.

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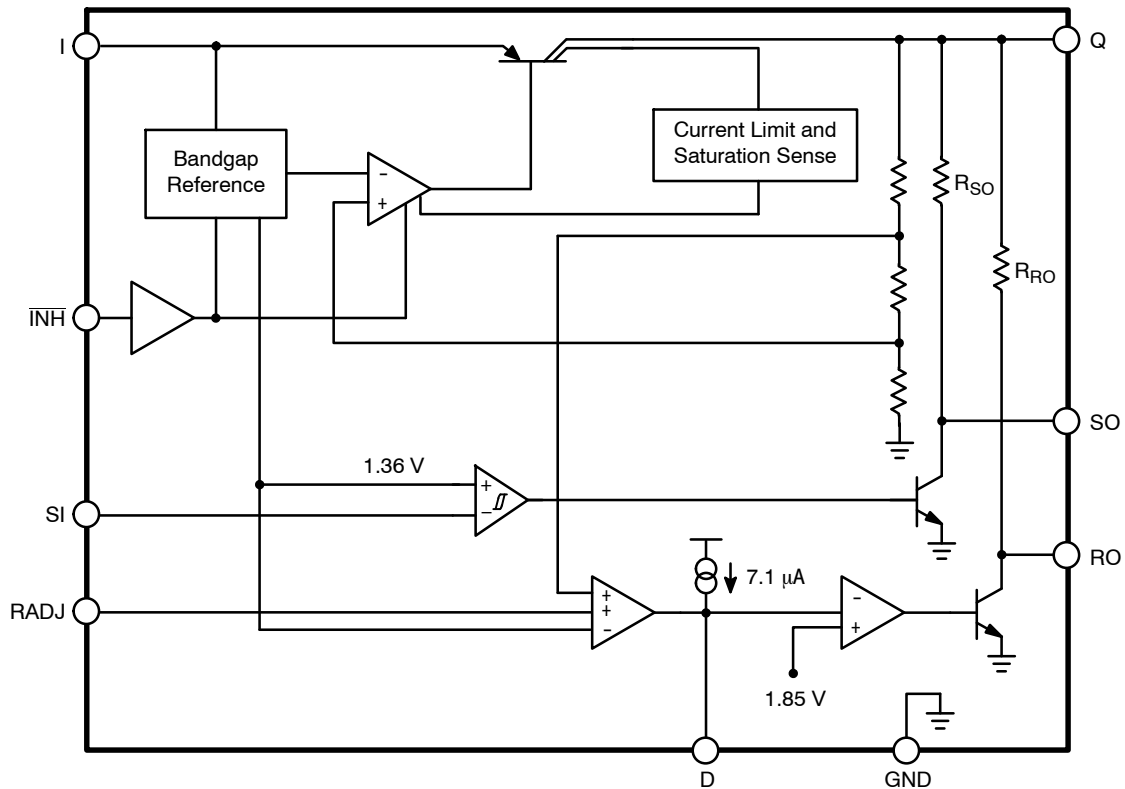


**Figure 1. SO-8 Simplified Block Diagram**

## PIN FUNCTION DESCRIPTION – SO-8 PACKAGE

Pin	Symbol	Description
1	I	Input. Battery Supply Input Voltage. Bypass directly to GND with ceramic capacitor.
2	SI	Sense Input. Can provide an early warning signal of an impending reset condition when used with SO. Connect to Q if not used.
3	RADJ	Reset Adjust. Use resistor divider to Q to adjust reset threshold lower. Connect to GND if not used.
4	D	Reset Delay. Connect external capacitor to ground to set delay time.
5	GND	Ground.
6	RO	Reset Output. NPN collector output with internal 20 kΩ pullup to Q. Notifies user of out of regulation condition. Leave open if not used.
7	SO	Sense Output. NPN collector output with internal 20 kΩ pullup to Q. Can be used to provide early warning of an impending reset condition. Leave open if not used.
8	Q	5.0 V, 3.3 V, ±2%, 150 mA output. Use 22 µF, ESR < 4 Ω to ground.

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**Figure 2. Simplified Block Diagram**

## PIN FUNCTION DESCRIPTION

Pin No. SOIC-14	Symbol	Description
1	RADJ	Reset Adjust. Use resistor divider to Q to adjust reset threshold lower. Connect to GND if not used.
2	D	Reset Delay. Connect external capacitor to ground to set delay time.
3	GND	Ground
4	GND	Ground
5	GND	Ground
6	INH	Inhibit. Connect to I if not needed. A high turns the regulator on. Use a low pass filter if transients with slew rate in excess of 10 V/μs may be present on this pin during operation. See Figure 34 for details.
7	RO	Reset Output. NPN collector output with internal 20 kΩ pullup to Q. Notifies user of out of regulation condition.
8	SO	Sense Output. NPN collector output with internal 20 kΩ pullup to Q. Can be used to provide early warning of an impending reset condition.
9	Q	5.0 V, 3.3 V, ±2%, 150 mA output. Use 22 μF, ESR < 4 Ω to ground.
10	GND	Ground
11	GND	Ground
12	GND	Ground
13	I	Input. Battery Supply Input Voltage.
14	SI	Sense Input. Can provide an early warning signal of an impending reset condition when used with SO.

**MAXIMUM RATINGS**

Rating	Symbol	Min	Max	Unit
Input Voltage to Regulator (DC)	$V_I$	-40	45	V
Input Peak Transient Voltage to Regulator wrt GND (Note 1)	-	-	60	V
Inhibit (INH)	$V_{INH}$	-40	45	V
Sense Input (SI)	$V_{SI}$	-40	45	V
Sense Input (SI)	$I_{SI}$	-1.0	1.0	mA
Reset Threshold (RADJ)	$V_{RADJ}$	-0.3	7.0	V
Reset Threshold (RADJ)	$I_{RADJ}$	-10	10	mA
Reset Delay (D)	$V_D$	-0.3	7.0	V
Reset Output (RO)	$V_{RO}$	-0.3	7.0	V
Reset Output (RO)	$I_{RO}$	-20	20	mA
Sense Output (SO)	$V_{SO}$	-0.3	7.0	V
Output (Q)	$V_Q$	-0.3	16	V
Output (Q)	$I_Q$	-5.0	-	mA
ESD Capability, Human Body Model (Note 3)	$ESD_{HB}$	2.0	-	kV
ESD Capability, Machine Model (Note 3)	$ESD_{MM}$	200	-	V
ESD Capability, Charged Device Model (Note 3)	$ESD_{CDM}$	1.0	-	kV
Junction Temperature	$T_J$	-	150	°C
Storage Temperature	$T_{stg}$	-50	150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

**RECOMMENDED OPERATING RANGE**

Input Voltage	5.0 V Version 3.3 V Version	$V_I$	5.5 4.4	45 45	V
Junction Temperature		$T_J$	-40	150	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

**LEAD TEMPERATURE SOLDERING REFLOW (Note 2)**

Reflow (SMD styles only), lead free 60 s–150 sec above 217, 40 sec max at peak	$T_{SLD}$	-	265 Pk	°C
Moisture Sensitivity Level	SO-8 SO-14	MSL	Level 1 Level 1	

1. Load Dump Test B (with centralized load dump suppression) according to ISO16750-2 standard. Guaranteed by design. Not tested in production. Passed Class C according to ISO16750-1
2. Per IPC / JEDEC J-STD-020C.
3. This device series incorporates ESD protection and is tested by the following methods:  
 ESD HBM tested per AEC-Q100-002 (JS-001-2010)  
 ESD MM tested per AEC-Q100-003 (EIA/JESD22-A115)  
 ESD CDM tested per AEC-Q100-011 (EIA/JESD22-C101).

**THERMAL CHARACTERISTICS**

Characteristic	Test Conditions (Typical Value)			Unit
	Note 4	Note 5	Note 6	
Thermal Characteristics, SO-8 Junction-to-Lead ( $\psi_{JLx}, \theta_{JLx}$ ) Junction-to-Ambient ( $R_{\theta JA}, \theta_{JA}$ )	72	58	58.3	°C/W
	198	150.7	124.5	
Thermal Characteristics, SO-14 Junction-to-Lead ( $\psi_{JLx}, \theta_{JLx}$ ) Junction-to-Ambient ( $R_{\theta JA}, \theta_{JA}$ )	15.1	19.9	19.3	°C/W
	142.7	101.2	86.1	
Thermal Characteristics, TSSOP-14 EP Junction-to-Tab ( $\psi_{JLx}, \theta_{JLx}$ ) Junction-to-Ambient ( $R_{\theta JA}, \theta_{JA}$ )	9.7	11.4	11.7	°C/W
	111.6	78.7	53.7	

4. 2 oz Copper, 50 mm sq Copper area, 1.5 mm thick FR4.
5. 2 oz Copper, 150 mm sq Copper area, 1.5 mm thick FR4.
6. 2 oz Copper, 500 mm sq Copper area, 1.5 mm thick FR4.

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## ELECTRICAL CHARACTERISTICS (-40°C < T<sub>J</sub> < 150°C; V<sub>I</sub> = 13.5 V unless otherwise noted.)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>OUTPUT Q</b>						
Output Voltage (5.0 V Version)	V <sub>Q</sub>	1.0 mA < I <sub>Q</sub> < 150 mA, 6.0 V < V <sub>I</sub> < 16 V	4.9	5.0	5.1	V
Output Voltage (3.3 V Version)	V <sub>Q</sub>	1.0 mA < I <sub>Q</sub> < 150 mA, 5.5 V < V <sub>I</sub> < 16 V	3.23	3.3	3.37	V
Current Limit	I <sub>Q</sub>	V <sub>Q</sub> = 90% of V <sub>Qnom</sub>	250	430	500	mA
Quiescent Current (I <sub>q</sub> = I <sub>I</sub> - I <sub>Q</sub> )	I <sub>q</sub>	INH ON, I <sub>Q</sub> < 100 μA, T <sub>J</sub> = 25°C	-	80	90	μA
Quiescent Current (I <sub>q</sub> = I <sub>I</sub> - I <sub>Q</sub> )	I <sub>q</sub>	INH ON, I <sub>Q</sub> < 100 μA, T <sub>J</sub> ≤ 125°C	-	80	95	μA
Quiescent Current (I <sub>q</sub> = I <sub>I</sub> - I <sub>Q</sub> )	I <sub>q</sub>	INH ON, I <sub>Q</sub> = 10 mA	-	200	500	μA
Quiescent Current (I <sub>q</sub> = I <sub>I</sub> - I <sub>Q</sub> )	I <sub>q</sub>	INH ON, I <sub>Q</sub> = 50 mA	-	0.8	2.0	mA
Quiescent Current (I <sub>q</sub> = I <sub>I</sub> - I <sub>Q</sub> )	I <sub>q</sub>	INH = 0 V, T <sub>J</sub> = 25°C	-	-	1.0	μA
Dropout Voltage (Note 7)	V <sub>dr</sub>	I <sub>Q</sub> = 100 mA	-	0.26	0.50	V
Load Regulation	ΔV <sub>Q</sub>	I <sub>Q</sub> = 1.0 mA to 100 mA	-	1.0	30	mV
Line Regulation	ΔV <sub>Q</sub>	V <sub>I</sub> = 6.0 V to 28 V, I <sub>Q</sub> = 1.0 mA	-	2.0	25	mV
Power Supply Ripple Rejection	PSRR	f <sub>r</sub> = 100 Hz, V <sub>r</sub> = 1.0 V <sub>pp</sub> , I <sub>Q</sub> = 100 mA	-	66	-	dB

### INHIBIT (INH)

Inhibit Off Voltage	V <sub>INHOFF</sub>	V <sub>Q</sub> < 0.1 V	-	-	0.8	V
Inhibit On Voltage 5.0 V Version 3.3 V Version	V <sub>INHON</sub>	V <sub>Q</sub> > 4.9 V V <sub>Q</sub> > 3.23 V	3.5 3.5	- -	- -	V
Input Current	I <sub>INHON</sub> I <sub>INHOFF</sub>	INH = 5 V INH = 0 V	- -	3.8 0.01	10 2.0	μA

### RESET (RO)

Switching Threshold 5.0 V Version 3.3 V Version	V <sub>RT</sub>	-	4.50 2.96	4.67 3.07	4.80 3.16	V
Output Resistance	R <sub>RO</sub>	-	10	20	40	kΩ
Reset Output Low Voltage 5.0 V Version 3.3 V Version	V <sub>RO</sub>	V <sub>Q</sub> = 4.5 V, Internal R <sub>RO</sub> , I <sub>RO</sub> = -1.0 mA V <sub>Q</sub> = 2.96 V, Internal R <sub>RO</sub> , I <sub>RO</sub> = -1.0 mA	- -	0.05 0.05	0.40 0.40	V
Allowable External Reset Pullup Resistor	V <sub>ROext</sub>	External Resistor to Q	5.6	-	-	kΩ
Delay Upper Threshold	V <sub>UD</sub>	-	1.5	1.85	2.2	V
Delay Lower Threshold	V <sub>LD</sub>	-	0.4	0.5	0.6	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

7. Only for 5 V version. Measured when the output voltage V<sub>Q</sub> has dropped 100 mV from the nominal value obtained at V<sub>I</sub> = 13.5 V.

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**ELECTRICAL CHARACTERISTICS (continued)** ( $-40^{\circ}\text{C} < T_J < 150^{\circ}\text{C}$ ;  $V_I = 13.5\text{ V}$  unless otherwise noted.)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>RESET (RO)</b>						
Delay Output Low Voltage 5.0 V Version 3.3 V Version	$V_{D,sat}$	$V_Q = 4.5\text{ V}$ , Internal $R_{RO}$ $V_Q = 2.96\text{ V}$ , Internal $R_{RO}$	- -	- 0.017	0.1 0.1	V
Delay Charge Current	$I_D$	$V_D = 1.0\text{ V}$	4.0	7.1	12	$\mu\text{A}$
Power On Reset Delay Time	$t_d$	$C_D = 100\text{ nF}$	17	28	35	ms
Reset Reaction Time	$t_{RR}$	$C_D = 100\text{ nF}$	0.5	1.6	4.0	$\mu\text{s}$
Reset Adjust Switching Threshold 5.0 V Version 3.3 V Version	$V_{RADJ,TH}$	$V_Q = 3.5\text{ V}$ $V_Q = 2.3\text{ V}$	1.26 1.26	1.36 1.36	1.44 1.44	V

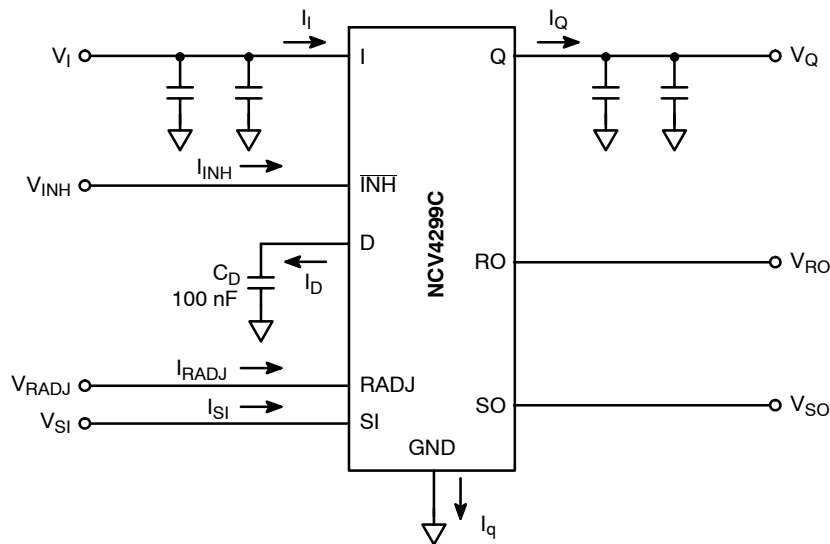
### INPUT VOLTAGE SENSE (SI and SO)

Sense Input Threshold High	$V_{SI,High}$	-	1.34	1.45	1.54	V
Sense Input Threshold Low	$V_{SI,Low}$	-	1.26	1.36	1.44	V
Sense Input Hysteresis	-	(Sense Threshold High) - (Sense Threshold Low)	50	90	130	mV
Sense Input Current	$I_{SI}$	$V_{SI} = 1.2\text{ V}$	-1.0	0.1	1.0	$\mu\text{A}$
Sense Output Resistance	$R_{SO}$	-	10	20	40	$\text{k}\Omega$
Sense Output Low Voltage	$V_{SO}$	$V_{SI} = 1.2\text{ V}$ , $V_I = 5.5\text{ V}$ , $I_{SO} = 0\text{ }\mu\text{A}$	-	0.1	0.4	V
Allowable External Sense Out Pullup Resistor	$R_{SOext}$	-	5.6	-	-	$\text{k}\Omega$
SI High to SO High Reaction Time	$t_{PSOLH}$	$R_{SOext} = 5.6\text{ k}\Omega$	-	1.3	8.0	$\mu\text{s}$
SI Low to SO Low Reaction Time	$t_{PSOHL}$	$R_{SOext} = 5.6\text{ k}\Omega$	-	2.2	5.0	$\mu\text{s}$

### THERMAL SHUTDOWN

Thermal Shutdown Temperature (Note 8)	$T_{SD}$	$I_{out} = 1\text{ mA}$	150	-	200	$^{\circ}\text{C}$
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8. Values based on design and/or characterization.



**Figure 3. Measurement Circuit**

TYPICAL PERFORMANCE CHARACTERISTICS – 5.0 V OPTION

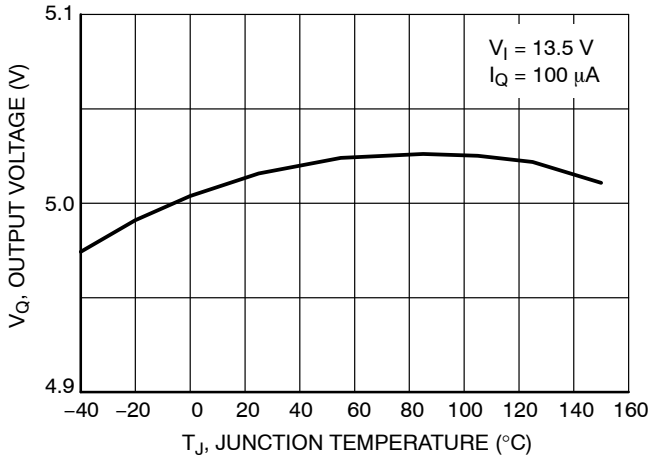


Figure 4. Output Voltage vs. Junction Temperature

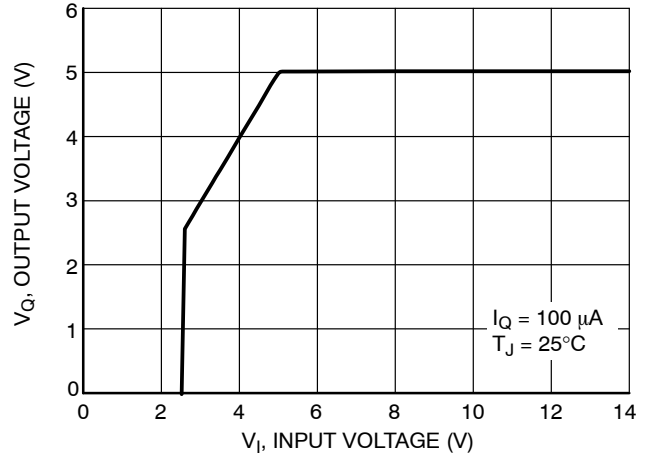


Figure 5. Output Voltage vs. Input Voltage

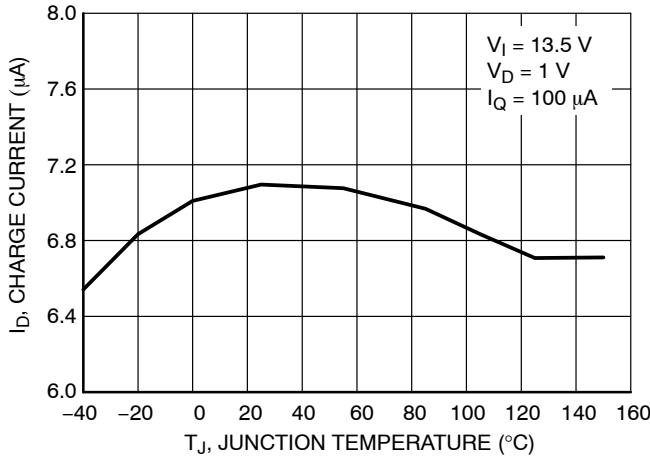


Figure 6. Charge Current vs. Junction Temperature

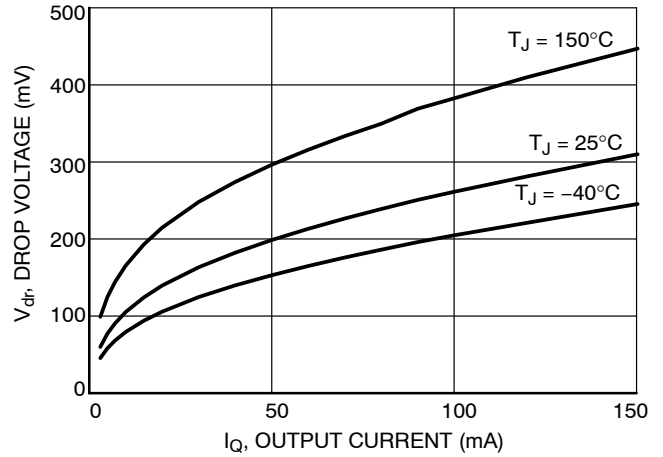


Figure 7. Drop Voltage vs. Output Current

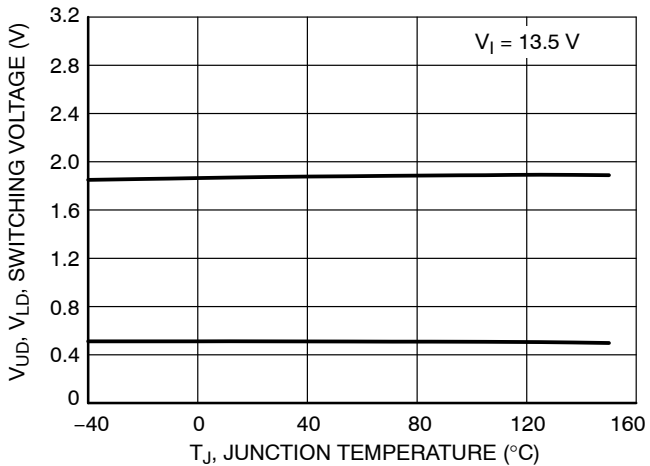


Figure 8. Switching Voltage vs. Junction Temperature

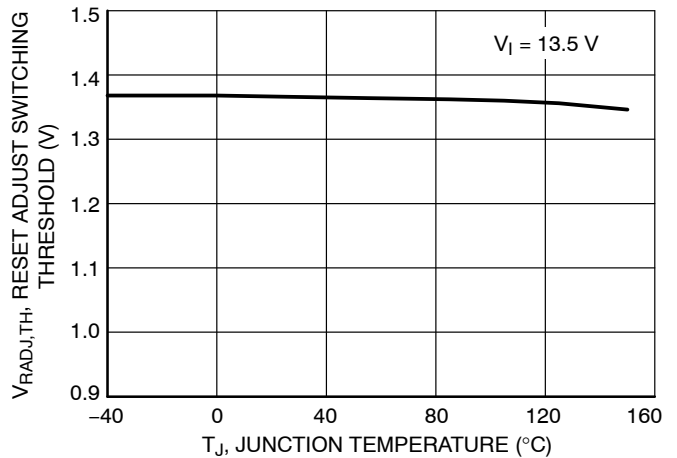


Figure 9. Reset Adjust Switching Threshold vs. Junction Temperature

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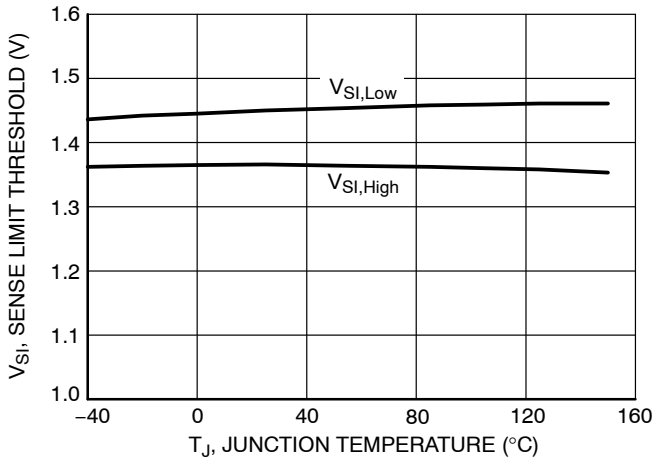


Figure 10. Sense Threshold vs. Junction Temperature

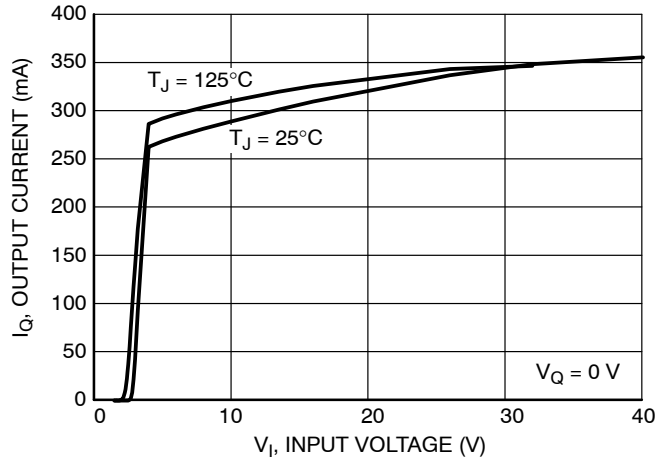


Figure 11. Output Current vs. Input Voltage

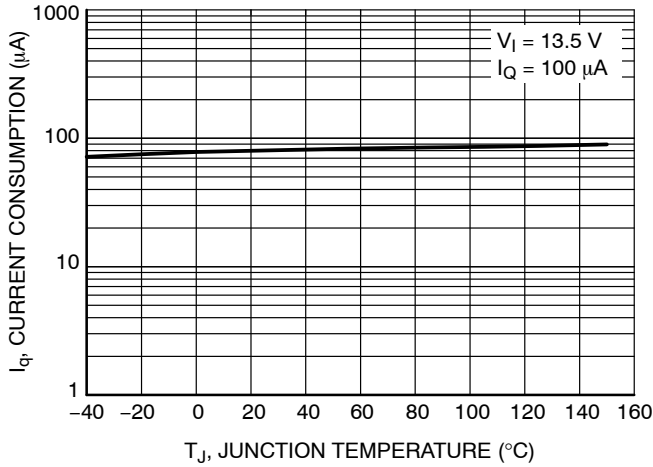


Figure 12. Current Consumption vs. Junction Temperature

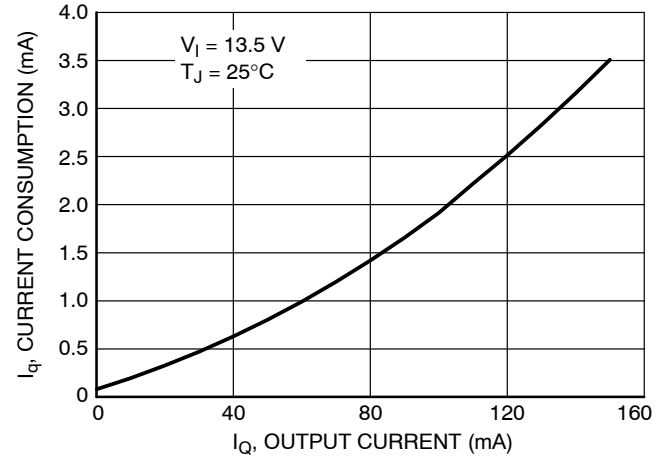


Figure 13. Current Consumption vs. Output Current

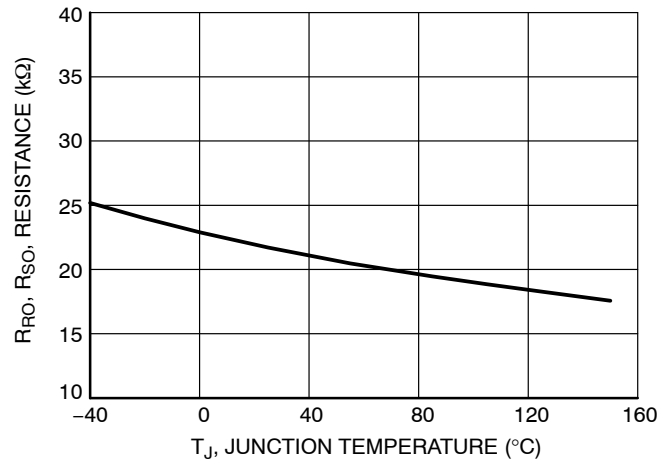


Figure 14.  $R_{RO}$ ,  $R_{SO}$  Resistance vs. Junction Temperature

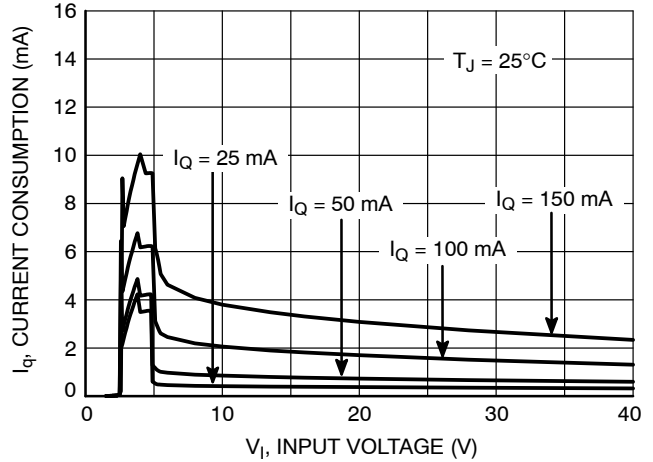
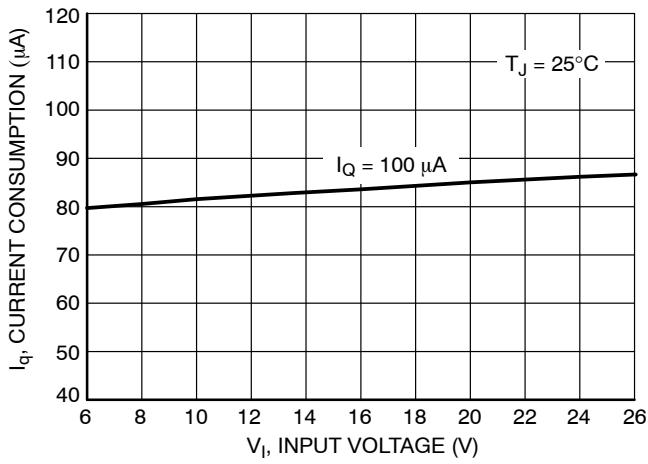


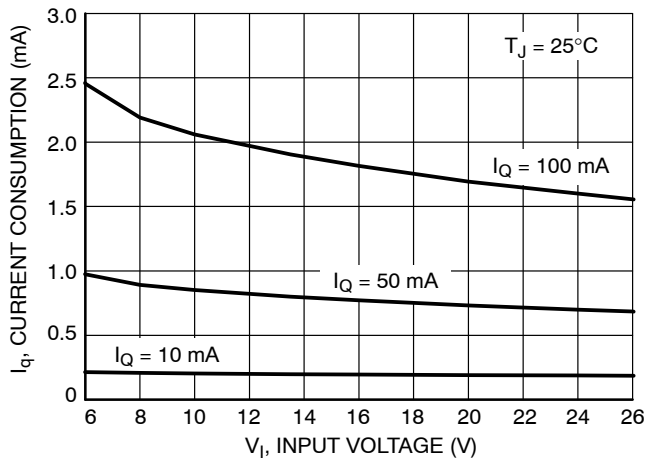
Figure 15. Current Consumption vs. Input Voltage



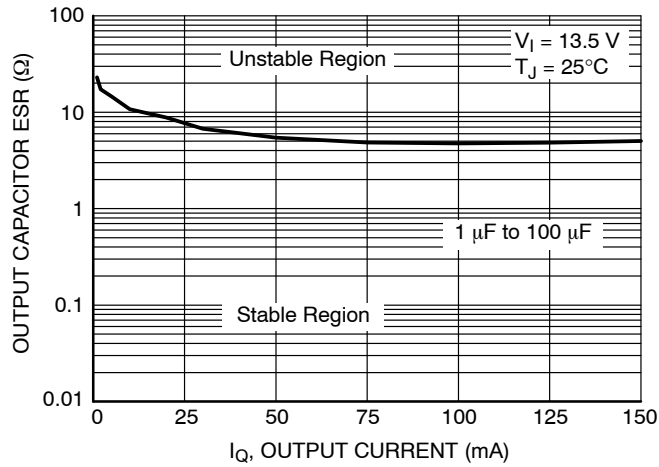
# NCV4299C



**Figure 16. Current Consumption vs. Input Voltage**



**Figure 17. Current Consumption vs. Input Voltage**



**Figure 18. Output Stability vs. Output Capacitor ESR**

TYPICAL PERFORMANCE CHARACTERISTICS – 3.3 V OPTION

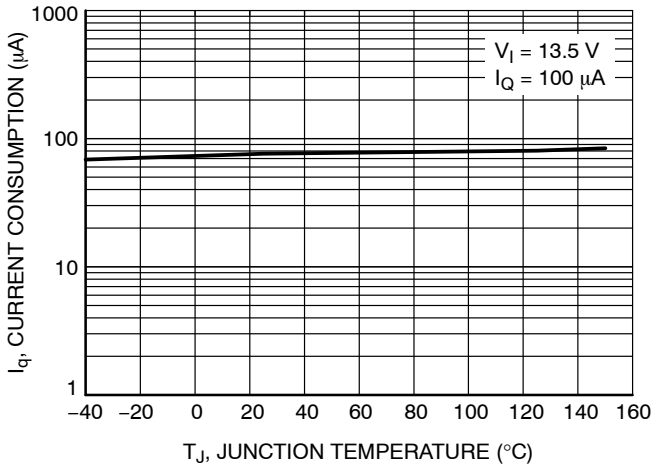


Figure 19. Current Consumption vs. Junction Temperature

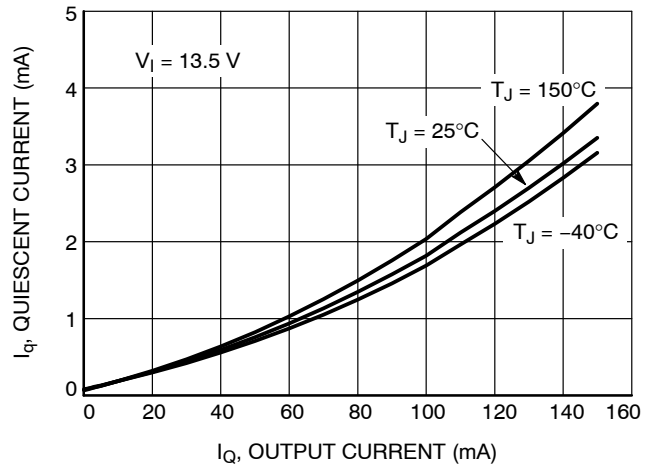


Figure 20. Current Consumption vs. Output Current

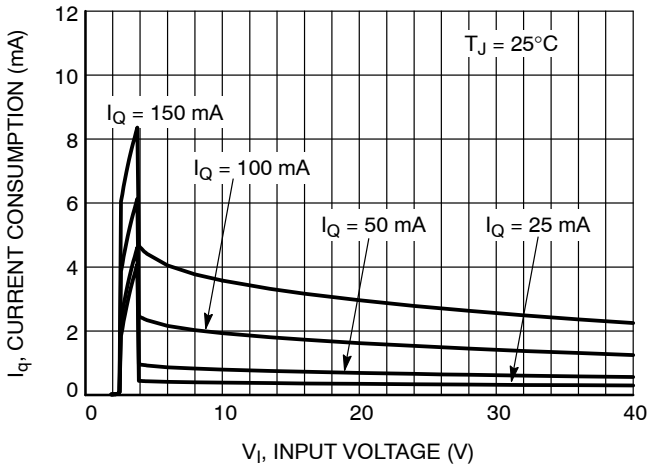


Figure 21. Current Consumption vs. Input Voltage

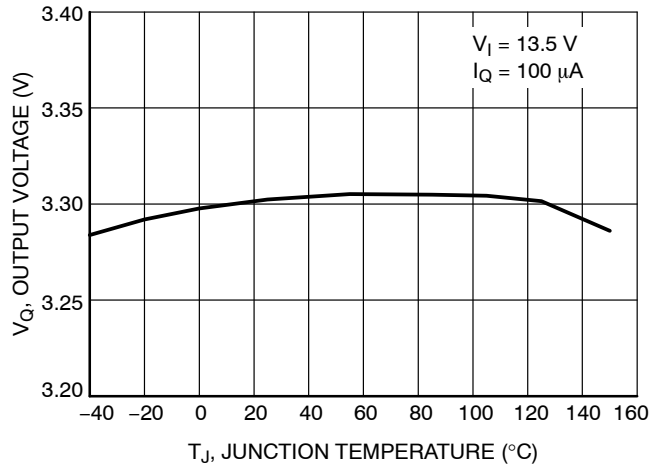


Figure 22. Output Voltage vs. Junction Temperature

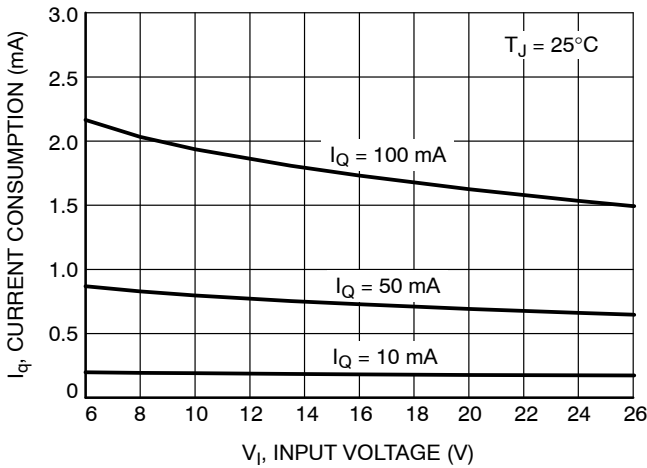


Figure 23. Current Consumption vs. Input Voltage

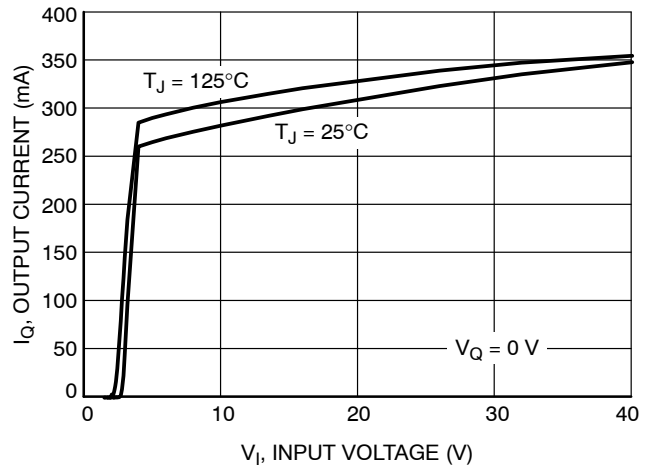


Figure 24. Output Current vs. Input Voltage

TYPICAL PERFORMANCE CHARACTERISTICS – 3.3 V OPTION

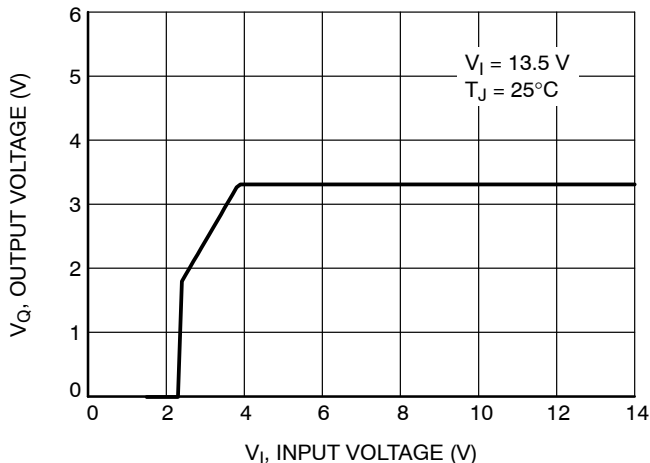


Figure 25. Output Voltage vs. Input Voltage

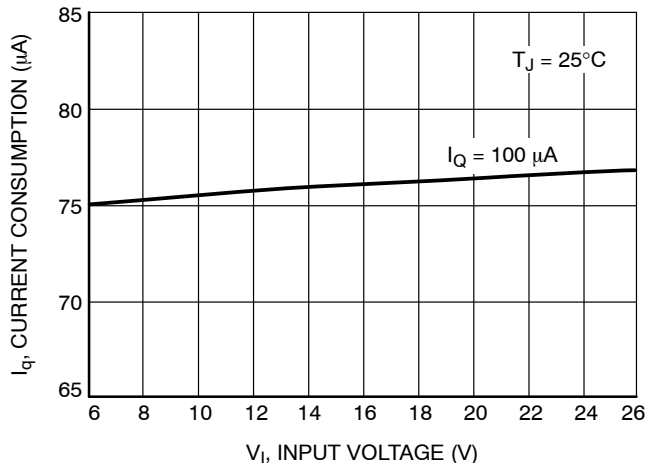


Figure 26. Current Consumption vs. Input Voltage

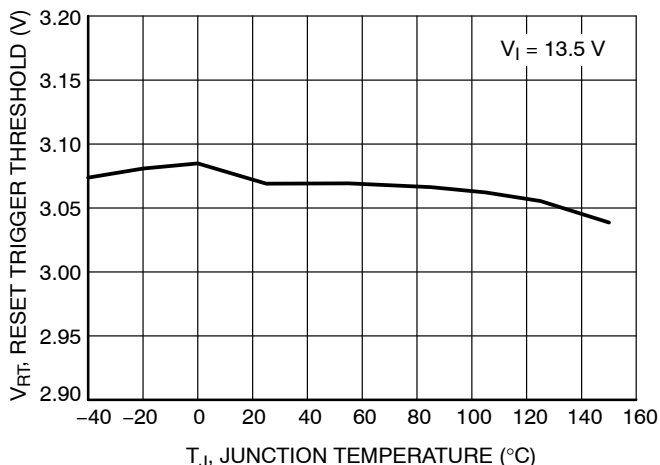


Figure 27. Reset Trigger Threshold vs. Junction Temperature

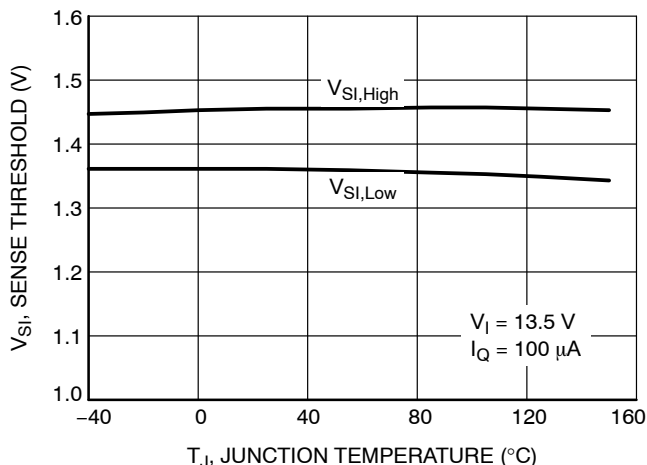


Figure 28. Sense Threshold vs. Junction Temperature

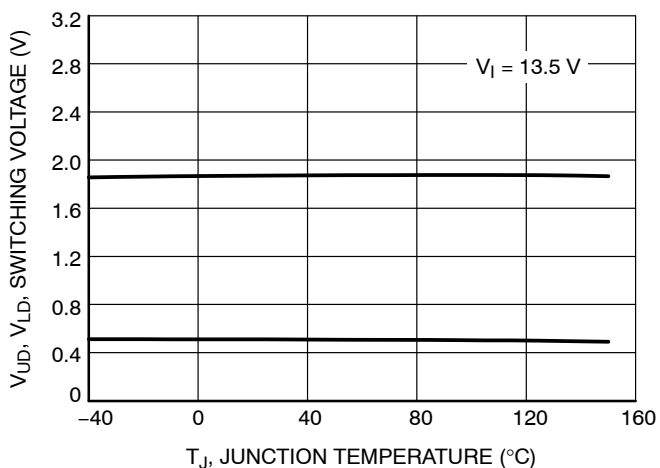


Figure 29. Switching Voltage vs. Junction Temperature

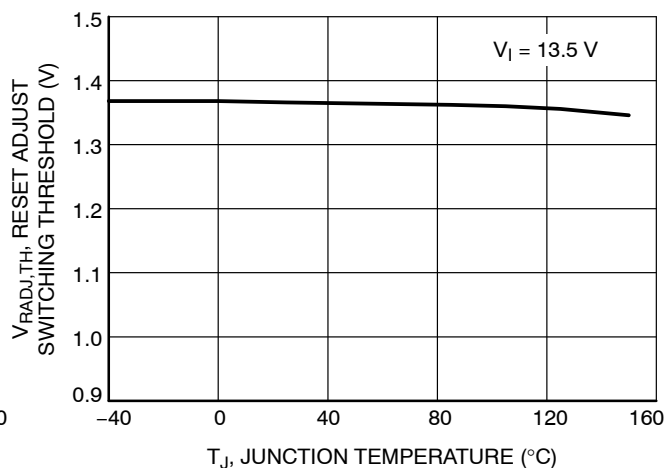


Figure 30. Reset Adjust Switching Threshold vs. Junction Temperature

TYPICAL PERFORMANCE CHARACTERISTICS – 3.3 V OPTION

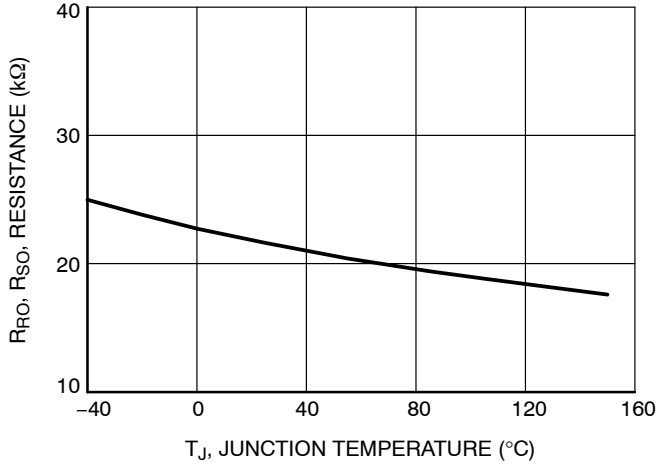


Figure 31. Resistance vs. Junction Temperature

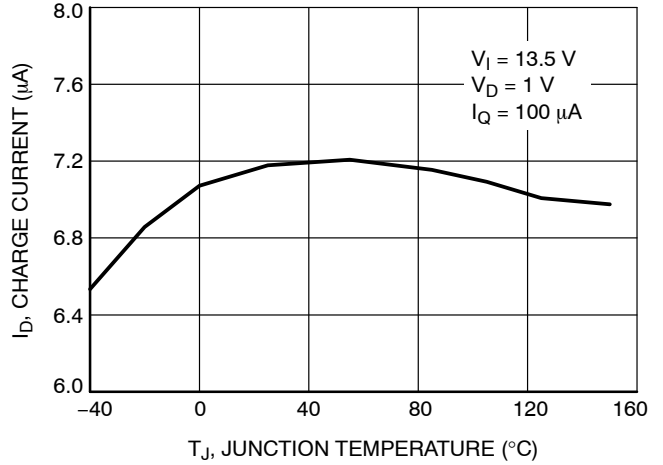


Figure 32. Charge Current vs. Junction Temperature

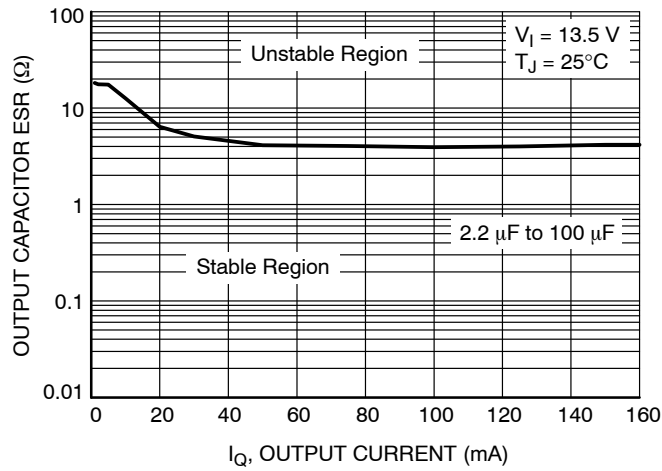


Figure 33. Output Capacitor ESR vs. Output Current

APPLICATION DESCRIPTION

**NCV4299C**

The NCV4299C is a family of precision micropower voltage regulators with an output current capability of 150 mA at 5.0 V and 3.3 V.

The output voltage is accurate within  $\pm 2\%$  with a maximum dropout voltage of 0.5 V at 100 mA. Low quiescent current is a feature drawing only 80  $\mu\text{A}$  with a 100  $\mu\text{A}$  load. This part is ideal for any and all battery operated microprocessor equipment.

Microprocessor control logic includes an active reset output RO (with delay), and a SI/SO monitor which can be used to provide an early warning signal to the microprocessor of a potential impending reset signal. The use of the SI/SO monitor allows the microprocessor to finish any signal processing before the reset shuts the microprocessor down. Internal output resistors on the RO and SO pins pulling up to the output pin Q reduce external component count. An inhibit function is available on the 14-lead part. With inhibit active, the regulator turns off and the device consumes less than 1.0  $\mu\text{A}$  of quiescent current.

The active reset circuit operates correctly at an output voltage as low as 1.0 V. The reset function is activated during the powerup sequence or during normal operation if the output voltage drops outside the regulation limits.

The reset threshold voltage can be decreased by the connection of an external resistor divider to the RADJ lead. The regulator is protected against reverse battery, short circuit, and thermal overload conditions. The device can withstand load dump transients making it suitable for use in automotive environments.

**NCV4299C Circuit Description**

The low dropout regulator in the NCV4299C uses a PNP pass transistor to give the lowest possible dropout voltage capability. The current is internally monitored to prevent oversaturation of the device and to limit current during over current conditions. Additional circuitry is provided to protect the device during overtemperature operation.

The regulator provides an output regulated to 2%.

Other features of the regulator include an undervoltage reset function and a sense circuit. The reset function has an adjustable time delay and an adjustable threshold level. The sense circuit trip level is adjustable and can be used as an early warning signal to the controller. An inhibit function that turns off the regulator and reduces the current consumption to less than 1.0  $\mu\text{A}$  is a feature available in the 14 pin package.

**Output Regulator**

The output is controlled by a precision trimmed reference. The PNP output has saturation control for regulation while the input voltage is low, preventing oversaturation. Current limit and voltage monitors complement the regulator design to give safe operating signals to the processor and control circuits.

**Stability Considerations**

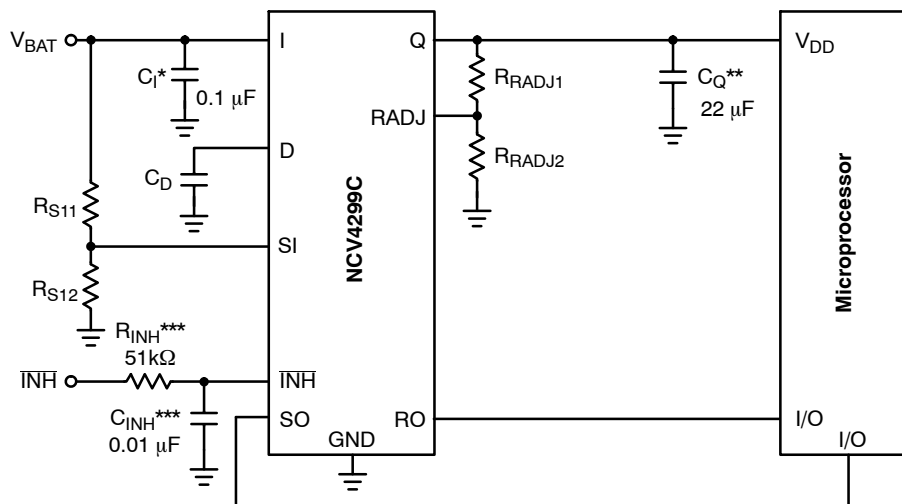
The input capacitor  $C_1$  is necessary for compensating input line reactance. Possible oscillations caused by input inductance and input capacitance can be damped by using a resistor of approximately 1.0  $\Omega$  in series with  $C_1$ .

The output or compensation capacitor helps determine three main characteristics of a linear regulator: startup delay, load transient response and loop stability.

The capacitor value and type should be based on cost, availability, size and temperature constraints. A tantalum or aluminum electrolytic capacitor is best, since a film or ceramic capacitor with almost zero ESR can cause instability. The aluminum electrolytic capacitor is the least expensive solution, but, if the circuit operates at low temperatures ( $-25^\circ\text{C}$  to  $-40^\circ\text{C}$ ), both the value and ESR of the capacitor will vary considerably. The capacitor manufacturer's data sheet usually provides this information.

The value for the output capacitor  $C_O$  shown in Figure 34 should work for most applications, however, it is not necessarily the optimized solution. Stability is guaranteed at values  $C_O \geq 22 \mu\text{F}$  and an  $\text{ESR} \leq 4 \Omega$  within the operating temperature range. Actual limits are shown in a graph in the typical performance characteristics section.

## NCV4299C

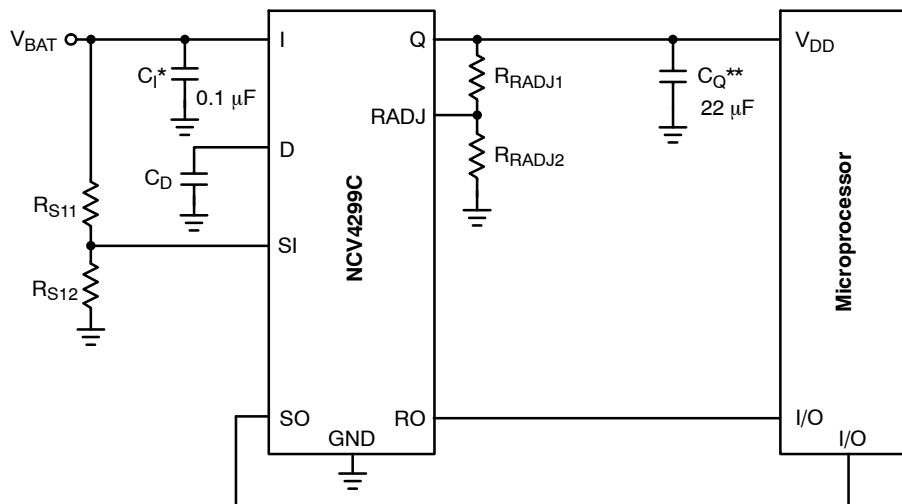


\*C<sub>1</sub> required if regulator is located far from the power supply filter.

\*\*C<sub>Q</sub> required for stability. Cap must operate at minimum temperature expected.

\*\*\*This RC filter is only required when transients with slew rate in excess of 10 V/μs may be present on the  $\overline{\text{INH}}$  voltage source during operation. The filter is not required when  $\overline{\text{INH}}$  is connected to a noise-free DC voltage.

**Figure 34. Test and Application Circuit Showing all Compensation and Sense Elements**



\*C<sub>1</sub> required if regulator is located far from the power supply filter.

\*\*C<sub>Q</sub> required for stability. Cap must operate at minimum temperature expected.

**Figure 35. Test and Application Circuit Showing all Compensation and Sense Elements for 8 Pin Package Part**

**Reset Output (RO)**

A reset signal, Reset Output (RO, low voltage) is generated as the IC powers up. After the output voltage  $V_Q$  increases above the reset threshold voltage  $V_{RT}$ , the delay timer D is started. When the voltage on the delay timer  $V_D$  passes  $V_{UD}$ , the reset signal RO goes high. D pin voltage in steady state is typically 2.5 V. A discharge of the delay timer ( $V_D$ ) is started when  $V_Q$  drops and stays below the reset

threshold voltage  $V_{RT}$ . When the voltage of the delay timer ( $V_D$ ) drops below the lower threshold voltage  $V_{LD}$ , the reset output voltage  $V_{RO}$  is brought low to reset the processor.

The reset output RO is an open collector NPN transistor, controlled by a low voltage detection circuit. The circuit is functionally independent of the rest of the IC, thereby guaranteeing that RO is valid for  $V_Q$  as low as 1.0 V.

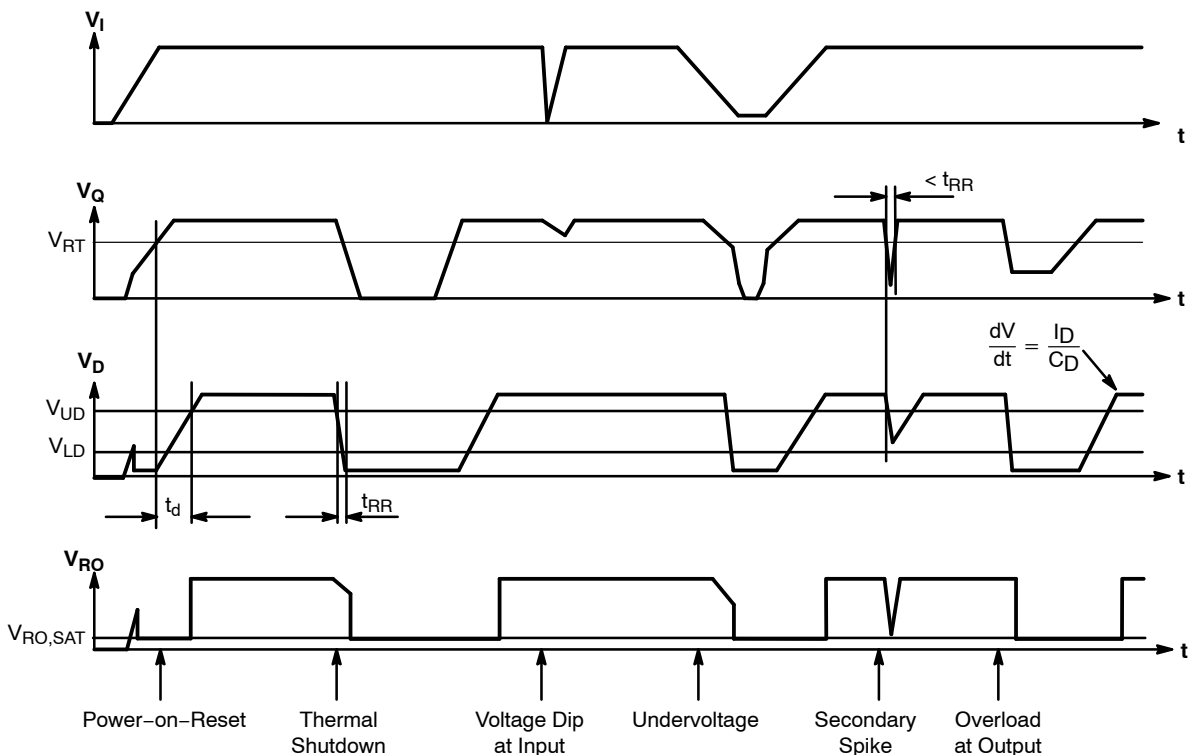


Figure 36. Reset Timing Diagram

**Reset Adjust (RADJ)**

The reset threshold  $V_{RT}$  can be decreased from a typical value of 4.67 V to as low as 3.5 V by using an external voltage divider connected from the Q lead to the pin RADJ, as shown in Figure 34. The resistor divider keeps the voltage above the  $V_{RADJ,TH}$  (typ. 1.36 V), for the desired input voltages and overrides the internal threshold detector. Adjust the voltage divider according to the following relationship:

$$V_{THRES} = V_{RADJ,TH} \cdot (R_{ADJ1} + R_{ADJ2}) / R_{ADJ2} \quad (\text{eq. 1})$$

If the reset adjust option is not needed, the RADJ-pin should be connected to GND causing the reset threshold to go to its default value (typ. 4.67 V).

**Reset Delay (D)**

The reset delay circuit provides a delay (programmable by capacitor  $C_D$ ) on the reset output RO lead. The delay lead D provides charge current  $I_D$  (typically 7.1  $\mu\text{A}$ ) to the external delay capacitor  $C_D$  during the following times:

1. During Powerup (once the regulation threshold has been exceeded).
2. After a reset event has occurred and the device is back in regulation. The delay capacitor is set to discharge when the regulation ( $V_{RT}$ , reset threshold voltage) has been violated. When the delay capacitor discharges to down to  $V_{LD}$ , the reset signal RO pulls low.

**Setting the Delay Time**

The delay time is set by the delay capacitor  $C_D$  and the charge current  $I_D$ . The time is measured by the delay capacitor voltage charging from the low level of  $V_{D,sat}$  to the higher level  $V_{UD}$ . The time delay follows the equation:

$$t_d = [C_D (V_{UD} - V_{D,sat})] / I_D \quad (\text{eq. 2})$$

Example:

Using  $C_D = 100 \text{ nF}$ .

Use the typical value for  $V_{D,sat} = 0.1 \text{ V}$ .

Use the typical value for  $V_{UD} = 1.85 \text{ V}$ .

Use the typical value for Delay Charge Current  $I_D = 7.1 \text{ }\mu\text{A}$ .

$$t_d = [100 \text{ nF}(1.85 - 0.1 \text{ V})] / 7.1 \text{ }\mu\text{A} = 24.6 \text{ ms} \quad (\text{eq. 3})$$

When the output voltage  $V_Q$  drops below the reset threshold voltage  $V_{RT}$ , the voltage on the delay capacitor  $V_D$  starts to drop. The time it takes to drop below the lower threshold voltage of  $V_{LD}$  is the reset reaction time,  $t_{RR}$ . This time is typically  $1.6 \text{ }\mu\text{s}$  for a delay capacitor of  $0.1 \text{ }\mu\text{F}$ . The reset reaction time can be estimated from the following relationship:

$$t_{RR} = 16 \text{ ns/nF} \times C_D \quad (\text{eq. 4})$$

**Sense Input (SI)/Sense Output (SO) Voltage Monitor**

An on-chip comparator is available to provide early warning to the microprocessor of a possible reset signal. The reset signal typically turns the microprocessor off instantaneously. This can cause unpredictable results with the microprocessor. The signal received from the SO pin will allow the microprocessor time to complete its present task before shutting down. This function is performed by a comparator referenced to the band gap voltage. The actual trip point can be programmed externally using a resistor divider to the input monitor (SI) (Figure 34). The typical threshold is  $1.36 \text{ V}$  on the SI Pin.

**Signal Output**

Figure 37 shows the SO Monitor waveforms as a result of the circuits depicted in Figure 34. As the output voltage  $V_Q$  falls, the monitor threshold  $V_{SI,Low}$  is crossed. This causes the voltage on the SO output to go low sending a warning signal to the microprocessor that a reset signal may occur in a short period of time.  $T_{WARNING}$  is the time the microprocessor has to complete the function it is currently working on and get ready for the reset shutdown signal. When the voltage on the SO goes low and the RO stays high the current consumption is typically  $400 \text{ }\mu\text{A}$ .

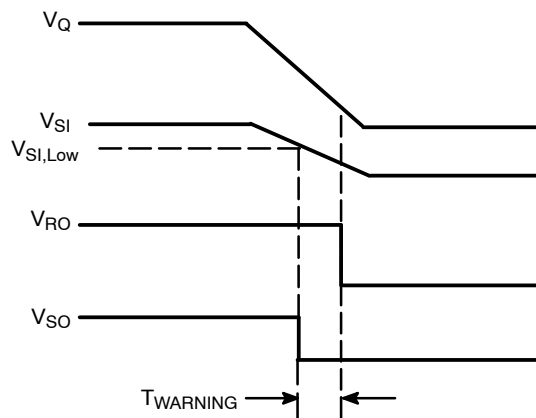


Figure 37. SO Warning Timing Waveform

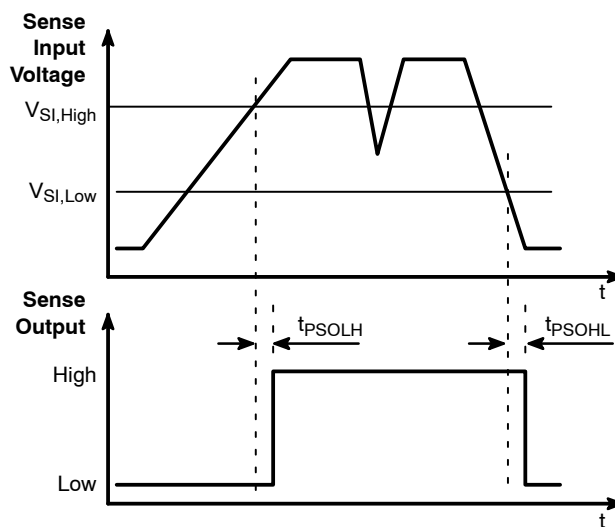


Figure 38. Sense Timing Diagram

**Calculating Power Dissipation in a Single Output Linear Regulator**

The maximum power dissipation for a single output regulator is:

$$P_{D(max)} = [V_{I(max)} - V_{Q(min)}] I_{Q(max)} + V_{I(max)} I_q \quad (\text{eq. 5})$$

where:

$V_{I(max)}$  is the maximum input voltage,

$V_{Q(min)}$  is the minimum output voltage,

$I_{Q(max)}$  is the maximum output current for the application, and

$I_q$  is the quiescent current the regulator consumes at  $I_{Q(max)}$ .

Once the value of  $P_{D(max)}$  is known, the maximum permissible value of  $R_{\theta JA}$  can be calculated:

$$R_{\theta JA} = (150^\circ\text{C} - T_A) / P_D \quad (\text{eq. 6})$$



The value of  $R_{\theta JA}$  can then be compared with those in the package section of the data sheet. Those packages with  $R_{\theta JA}$ 's less than the calculated value in Equation 6 will keep the die temperature below 150°C. In some cases, none of the packages will be sufficient to dissipate the heat generated by the IC, and an external heatsink will be required. Thermal Resistance  $R_{\theta JA}$  vs. Copper Area is shown in Figure 39.

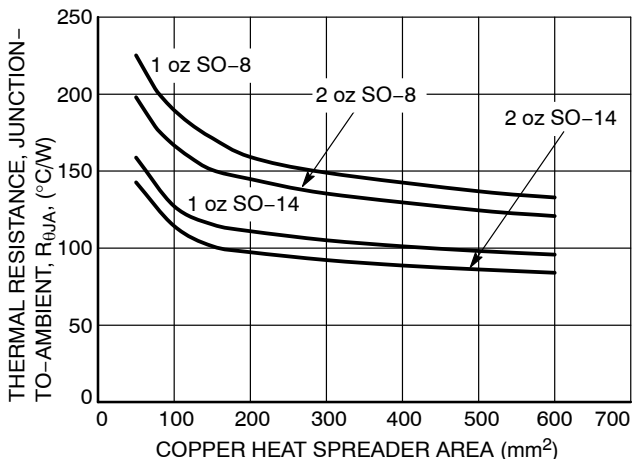


Figure 39. Thermal Resistance  $R_{\theta JA}$  vs. Copper Area

**Heatsinks**

A heatsink effectively increases the surface area of the package to improve the flow of heat away from the IC and into the surrounding air.

Each material in the heat flow path between the IC and the outside environment will have a thermal resistance. Like series electrical resistances, these resistances are summed to determine the value of  $R_{\theta JA}$ :

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CS} + R_{\theta SA} \quad (\text{eq. 7})$$

where:

$R_{\theta JC}$  = the junction-to-case thermal resistance,  
 $R_{\theta CS}$  = the case-to-heatsink thermal resistance, and  
 $R_{\theta SA}$  = the heatsink-to-ambient thermal resistance.

$R_{\theta JC}$  appears in the package section of the data sheet. Like  $R_{\theta JA}$ , it too is a function of package type.  $R_{\theta CS}$  and  $R_{\theta SA}$  are functions of the package type, heatsink and the interface between them. These values appear in heatsink data sheets of heatsink manufacturers. Thermal, mounting, and heatsinking are discussed in the ON Semiconductor application note AN1040/D, available on the ON Semiconductor website.

**ORDERING INFORMATION**

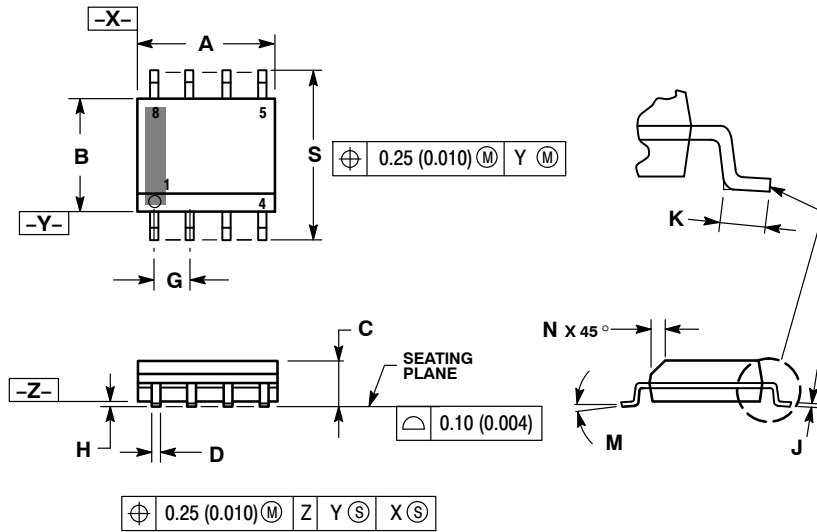
Device	Package	Shipping†
NCV4299CD133R2G	SO-8 (Pb-Free)	2500 / Tape & Reel
NCV4299CD150R2G	SO-8 (Pb-Free)	2500 / Tape & Reel
NCV4299CD233R2G	SO-14 (Pb-Free)	2500 / Tape & Reel
NCV4299CD250R2G	SO-14 (Pb-Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NCV4299C

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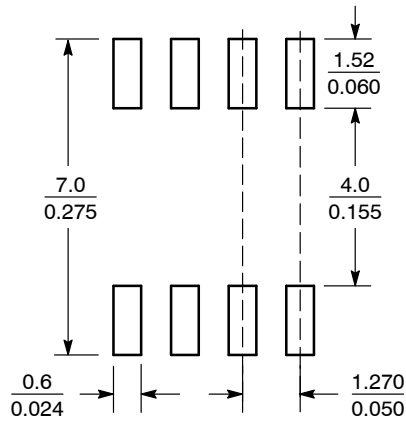


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

### SOLDERING FOOTPRINT\*



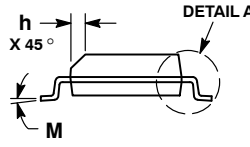
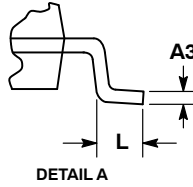
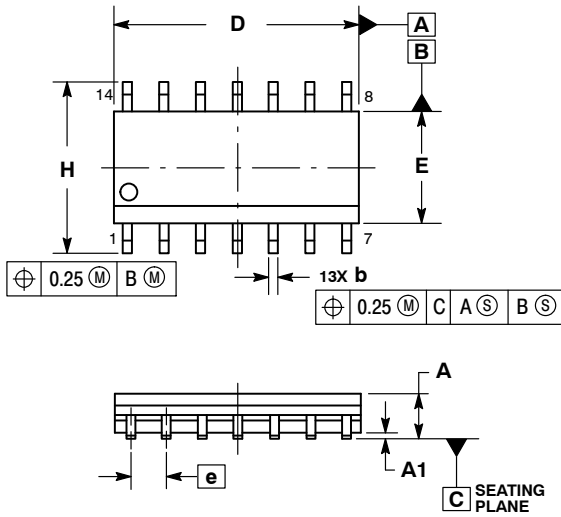
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\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# NCV4299C

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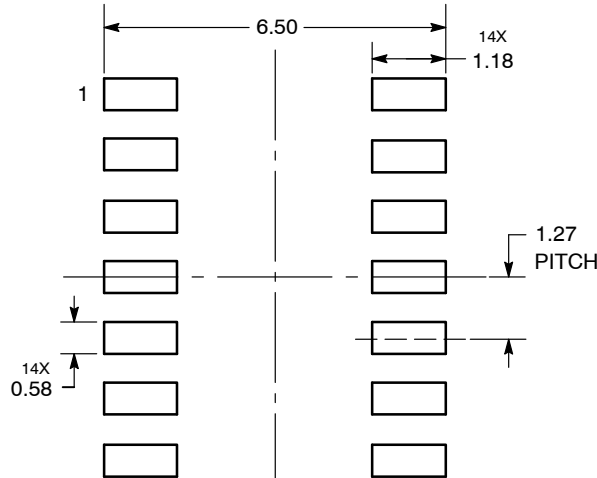


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5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0°	7°	0°	7°

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  3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
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### SOLDERING FOOTPRINT\*



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### GENERIC MARKING DIAGRAM\*



XXXXXX = Specific Device Code  
 A = Assembly Location  
 L = Wafer Lot  
 Y = Year  
 W = Work Week  
 ■ = Pb-Free Package

XXXXXX = Specific Device Code  
 A = Assembly Location  
 Y = Year  
 WW = Work Week  
 ■ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <p><b>STYLE 1:</b><br/> PIN 1. EMITTER<br/> 2. COLLECTOR<br/> 3. COLLECTOR<br/> 4. EMITTER<br/> 5. EMITTER<br/> 6. BASE<br/> 7. BASE<br/> 8. EMITTER</p>                                                                 | <p><b>STYLE 2:</b><br/> PIN 1. COLLECTOR, DIE, #1<br/> 2. COLLECTOR, #1<br/> 3. COLLECTOR, #2<br/> 4. COLLECTOR, #2<br/> 5. BASE, #2<br/> 6. EMITTER, #2<br/> 7. BASE, #1<br/> 8. EMITTER, #1</p>               | <p><b>STYLE 3:</b><br/> PIN 1. DRAIN, DIE #1<br/> 2. DRAIN, #1<br/> 3. DRAIN, #2<br/> 4. DRAIN, #2<br/> 5. GATE, #2<br/> 6. SOURCE, #2<br/> 7. GATE, #1<br/> 8. SOURCE, #1</p>                            | <p><b>STYLE 4:</b><br/> PIN 1. ANODE<br/> 2. ANODE<br/> 3. ANODE<br/> 4. ANODE<br/> 5. ANODE<br/> 6. ANODE<br/> 7. ANODE<br/> 8. COMMON CATHODE</p>                                                                           |
| <p><b>STYLE 5:</b><br/> PIN 1. DRAIN<br/> 2. DRAIN<br/> 3. DRAIN<br/> 4. DRAIN<br/> 5. GATE<br/> 6. GATE<br/> 7. SOURCE<br/> 8. SOURCE</p>                                                                               | <p><b>STYLE 6:</b><br/> PIN 1. SOURCE<br/> 2. DRAIN<br/> 3. DRAIN<br/> 4. SOURCE<br/> 5. SOURCE<br/> 6. GATE<br/> 7. GATE<br/> 8. SOURCE</p>                                                                    | <p><b>STYLE 7:</b><br/> PIN 1. INPUT<br/> 2. EXTERNAL BYPASS<br/> 3. THIRD STAGE SOURCE<br/> 4. GROUND<br/> 5. DRAIN<br/> 6. GATE 3<br/> 7. SECOND STAGE Vd<br/> 8. FIRST STAGE Vd</p>                    | <p><b>STYLE 8:</b><br/> PIN 1. COLLECTOR, DIE #1<br/> 2. BASE, #1<br/> 3. BASE, #2<br/> 4. COLLECTOR, #2<br/> 5. COLLECTOR, #2<br/> 6. EMITTER, #2<br/> 7. EMITTER, #1<br/> 8. COLLECTOR, #1</p>                              |
| <p><b>STYLE 9:</b><br/> PIN 1. EMITTER, COMMON<br/> 2. COLLECTOR, DIE #1<br/> 3. COLLECTOR, DIE #2<br/> 4. EMITTER, COMMON<br/> 5. EMITTER, COMMON<br/> 6. BASE, DIE #2<br/> 7. BASE, DIE #1<br/> 8. EMITTER, COMMON</p> | <p><b>STYLE 10:</b><br/> PIN 1. GROUND<br/> 2. BIAS 1<br/> 3. OUTPUT<br/> 4. GROUND<br/> 5. GROUND<br/> 6. BIAS 2<br/> 7. INPUT<br/> 8. GROUND</p>                                                              | <p><b>STYLE 11:</b><br/> PIN 1. SOURCE 1<br/> 2. GATE 1<br/> 3. SOURCE 2<br/> 4. GATE 2<br/> 5. DRAIN 2<br/> 6. DRAIN 2<br/> 7. DRAIN 1<br/> 8. DRAIN 1</p>                                               | <p><b>STYLE 12:</b><br/> PIN 1. SOURCE<br/> 2. SOURCE<br/> 3. SOURCE<br/> 4. GATE<br/> 5. DRAIN<br/> 6. DRAIN<br/> 7. DRAIN<br/> 8. DRAIN</p>                                                                                 |
| <p><b>STYLE 13:</b><br/> PIN 1. N.C.<br/> 2. SOURCE<br/> 3. SOURCE<br/> 4. GATE<br/> 5. DRAIN<br/> 6. DRAIN<br/> 7. DRAIN<br/> 8. DRAIN</p>                                                                              | <p><b>STYLE 14:</b><br/> PIN 1. N-SOURCE<br/> 2. N-GATE<br/> 3. P-SOURCE<br/> 4. P-GATE<br/> 5. P-DRAIN<br/> 6. P-DRAIN<br/> 7. N-DRAIN<br/> 8. N-DRAIN</p>                                                     | <p><b>STYLE 15:</b><br/> PIN 1. ANODE 1<br/> 2. ANODE 1<br/> 3. ANODE 1<br/> 4. ANODE 1<br/> 5. CATHODE, COMMON<br/> 6. CATHODE, COMMON<br/> 7. CATHODE, COMMON<br/> 8. CATHODE, COMMON</p>               | <p><b>STYLE 16:</b><br/> PIN 1. EMITTER, DIE #1<br/> 2. BASE, DIE #1<br/> 3. EMITTER, DIE #2<br/> 4. BASE, DIE #2<br/> 5. COLLECTOR, DIE #2<br/> 6. COLLECTOR, DIE #2<br/> 7. COLLECTOR, DIE #1<br/> 8. COLLECTOR, DIE #1</p> |
| <p><b>STYLE 17:</b><br/> PIN 1. VCC<br/> 2. V2OUT<br/> 3. V1OUT<br/> 4. TXE<br/> 5. RXE<br/> 6. VEE<br/> 7. GND<br/> 8. ACC</p>                                                                                          | <p><b>STYLE 18:</b><br/> PIN 1. ANODE<br/> 2. ANODE<br/> 3. SOURCE<br/> 4. GATE<br/> 5. DRAIN<br/> 6. DRAIN<br/> 7. CATHODE<br/> 8. CATHODE</p>                                                                 | <p><b>STYLE 19:</b><br/> PIN 1. SOURCE 1<br/> 2. GATE 1<br/> 3. SOURCE 2<br/> 4. GATE 2<br/> 5. DRAIN 2<br/> 6. MIRROR 2<br/> 7. DRAIN 1<br/> 8. MIRROR 1</p>                                             | <p><b>STYLE 20:</b><br/> PIN 1. SOURCE (N)<br/> 2. GATE (N)<br/> 3. SOURCE (P)<br/> 4. GATE (P)<br/> 5. DRAIN<br/> 6. DRAIN<br/> 7. DRAIN<br/> 8. DRAIN</p>                                                                   |
| <p><b>STYLE 21:</b><br/> PIN 1. CATHODE 1<br/> 2. CATHODE 2<br/> 3. CATHODE 3<br/> 4. CATHODE 4<br/> 5. CATHODE 5<br/> 6. COMMON ANODE<br/> 7. COMMON ANODE<br/> 8. CATHODE 6</p>                                        | <p><b>STYLE 22:</b><br/> PIN 1. I/O LINE 1<br/> 2. COMMON CATHODE/VCC<br/> 3. COMMON CATHODE/VCC<br/> 4. I/O LINE 3<br/> 5. COMMON ANODE/GND<br/> 6. I/O LINE 4<br/> 7. I/O LINE 5<br/> 8. COMMON ANODE/GND</p> | <p><b>STYLE 23:</b><br/> PIN 1. LINE 1 IN<br/> 2. COMMON ANODE/GND<br/> 3. COMMON ANODE/GND<br/> 4. LINE 2 IN<br/> 5. LINE 2 OUT<br/> 6. COMMON ANODE/GND<br/> 7. COMMON ANODE/GND<br/> 8. LINE 1 OUT</p> | <p><b>STYLE 24:</b><br/> PIN 1. BASE<br/> 2. EMITTER<br/> 3. COLLECTOR/ANODE<br/> 4. COLLECTOR/ANODE<br/> 5. CATHODE<br/> 6. CATHODE<br/> 7. COLLECTOR/ANODE<br/> 8. COLLECTOR/ANODE</p>                                      |
| <p><b>STYLE 25:</b><br/> PIN 1. VIN<br/> 2. N/C<br/> 3. REXT<br/> 4. GND<br/> 5. IOUT<br/> 6. IOUT<br/> 7. IOUT<br/> 8. IOUT</p>                                                                                         | <p><b>STYLE 26:</b><br/> PIN 1. GND<br/> 2. dv/dt<br/> 3. ENABLE<br/> 4. ILIMIT<br/> 5. SOURCE<br/> 6. SOURCE<br/> 7. SOURCE<br/> 8. VCC</p>                                                                    | <p><b>STYLE 27:</b><br/> PIN 1. ILIMIT<br/> 2. OVLO<br/> 3. UVLO<br/> 4. INPUT+<br/> 5. SOURCE<br/> 6. SOURCE<br/> 7. SOURCE<br/> 8. DRAIN</p>                                                            | <p><b>STYLE 28:</b><br/> PIN 1. SW_TO_GND<br/> 2. DASIC_OFF<br/> 3. DASIC_SW_DET<br/> 4. GND<br/> 5. V_MON<br/> 6. VBULK<br/> 7. VBULK<br/> 8. VIN</p>                                                                        |
| <p><b>STYLE 29:</b><br/> PIN 1. BASE, DIE #1<br/> 2. EMITTER, #1<br/> 3. BASE, #2<br/> 4. EMITTER, #2<br/> 5. COLLECTOR, #2<br/> 6. COLLECTOR, #2<br/> 7. COLLECTOR, #1<br/> 8. COLLECTOR, #1</p>                        | <p><b>STYLE 30:</b><br/> PIN 1. DRAIN 1<br/> 2. DRAIN 1<br/> 3. GATE 2<br/> 4. SOURCE 2<br/> 5. SOURCE 1/DRAIN 2<br/> 6. SOURCE 1/DRAIN 2<br/> 7. SOURCE 1/DRAIN 2<br/> 8. GATE 1</p>                           |                                                                                                                                                                                                           |                                                                                                                                                                                                                               |

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# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor®



SCALE 1:1

SOIC-14 NB  
CASE 751A-03  
ISSUE L

DATE 03 FEB 2016



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0°	7°	0°	7°

SOLDERING FOOTPRINT\*



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM\*



- XXXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- Y = Year
- WW = Work Week
- G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

STYLES ON PAGE 2

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**SOIC-14**  
**CASE 751A-03**  
**ISSUE L**

DATE 03 FEB 2016

STYLE 1:  
 PIN 1. COMMON CATHODE  
 2. ANODE/CATHODE  
 3. ANODE/CATHODE  
 4. NO CONNECTION  
 5. ANODE/CATHODE  
 6. NO CONNECTION  
 7. ANODE/CATHODE  
 8. ANODE/CATHODE  
 9. ANODE/CATHODE  
 10. NO CONNECTION  
 11. ANODE/CATHODE  
 12. ANODE/CATHODE  
 13. NO CONNECTION  
 14. COMMON ANODE

STYLE 2:  
 CANCELLED

STYLE 3:  
 PIN 1. NO CONNECTION  
 2. ANODE  
 3. ANODE  
 4. NO CONNECTION  
 5. ANODE  
 6. NO CONNECTION  
 7. ANODE  
 8. ANODE  
 9. ANODE  
 10. NO CONNECTION  
 11. ANODE  
 12. ANODE  
 13. NO CONNECTION  
 14. COMMON CATHODE

STYLE 4:  
 PIN 1. NO CONNECTION  
 2. CATHODE  
 3. CATHODE  
 4. NO CONNECTION  
 5. CATHODE  
 6. NO CONNECTION  
 7. CATHODE  
 8. CATHODE  
 9. CATHODE  
 10. NO CONNECTION  
 11. CATHODE  
 12. CATHODE  
 13. NO CONNECTION  
 14. COMMON ANODE

STYLE 5:  
 PIN 1. COMMON CATHODE  
 2. ANODE/CATHODE  
 3. ANODE/CATHODE  
 4. ANODE/CATHODE  
 5. ANODE/CATHODE  
 6. NO CONNECTION  
 7. COMMON ANODE  
 8. COMMON CATHODE  
 9. ANODE/CATHODE  
 10. ANODE/CATHODE  
 11. ANODE/CATHODE  
 12. ANODE/CATHODE  
 13. NO CONNECTION  
 14. COMMON ANODE

STYLE 6:  
 PIN 1. CATHODE  
 2. CATHODE  
 3. CATHODE  
 4. CATHODE  
 5. CATHODE  
 6. CATHODE  
 7. CATHODE  
 8. ANODE  
 9. ANODE  
 10. ANODE  
 11. ANODE  
 12. ANODE  
 13. ANODE  
 14. ANODE

STYLE 7:  
 PIN 1. ANODE/CATHODE  
 2. COMMON ANODE  
 3. COMMON CATHODE  
 4. ANODE/CATHODE  
 5. ANODE/CATHODE  
 6. ANODE/CATHODE  
 7. ANODE/CATHODE  
 8. ANODE/CATHODE  
 9. ANODE/CATHODE  
 10. ANODE/CATHODE  
 11. COMMON CATHODE  
 12. COMMON ANODE  
 13. ANODE/CATHODE  
 14. ANODE/CATHODE

STYLE 8:  
 PIN 1. COMMON CATHODE  
 2. ANODE/CATHODE  
 3. ANODE/CATHODE  
 4. NO CONNECTION  
 5. ANODE/CATHODE  
 6. ANODE/CATHODE  
 7. COMMON ANODE  
 8. COMMON ANODE  
 9. ANODE/CATHODE  
 10. ANODE/CATHODE  
 11. NO CONNECTION  
 12. ANODE/CATHODE  
 13. ANODE/CATHODE  
 14. COMMON CATHODE

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